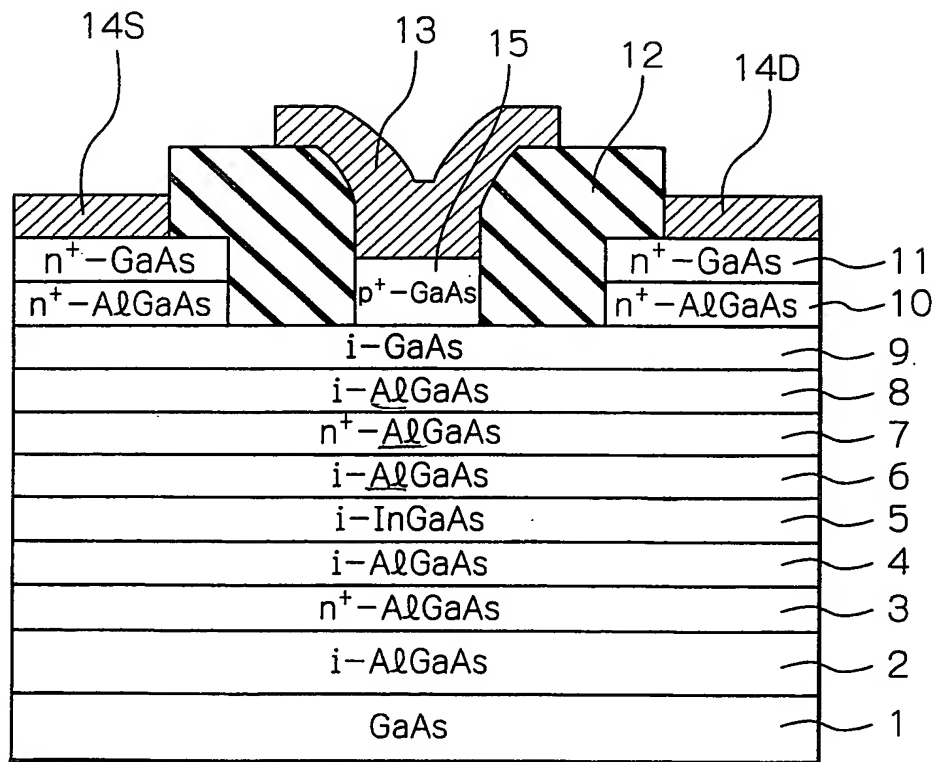




Inventors: Yasunori BITO
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 Ref. No.: Q78644
 For: HETEROJUNCTION FIELD EFFECT TYPE SEMICONDUCTOR
 DEVICE HAVING HIGH GATE TURN-ON VOLTAGE AND LOW ON-
 RESISTANCE AND ITS MANUFACTURING METHOD
 REPLACEMENT SHEET

Fig. 4



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Fig. 8

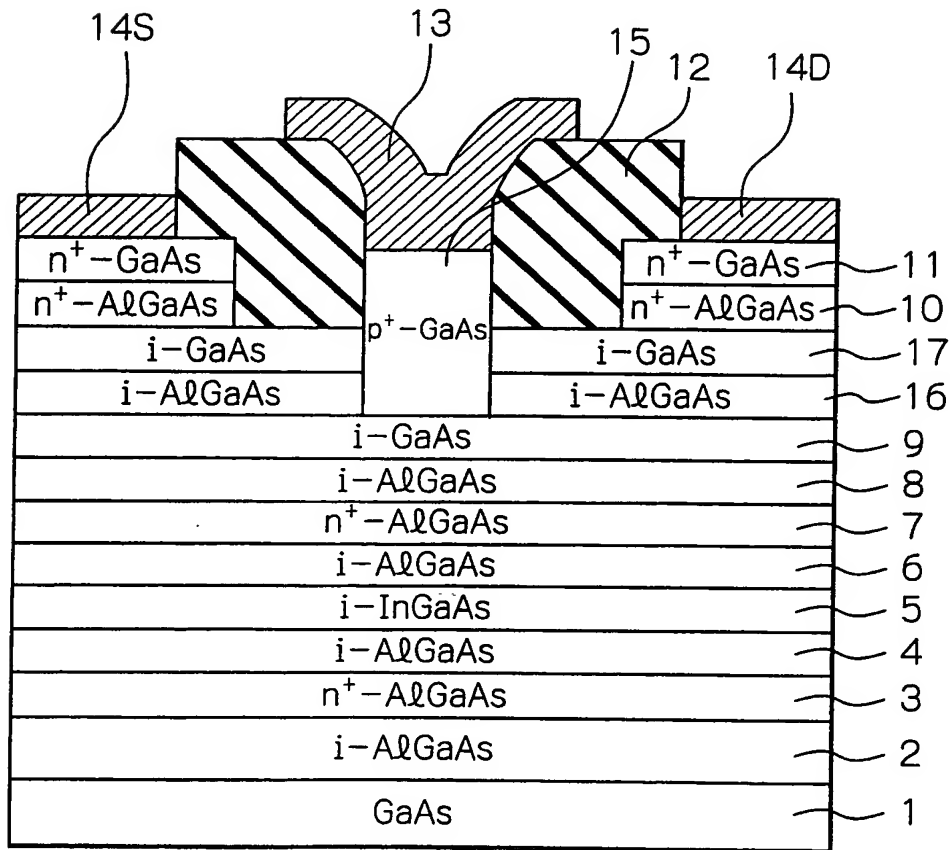
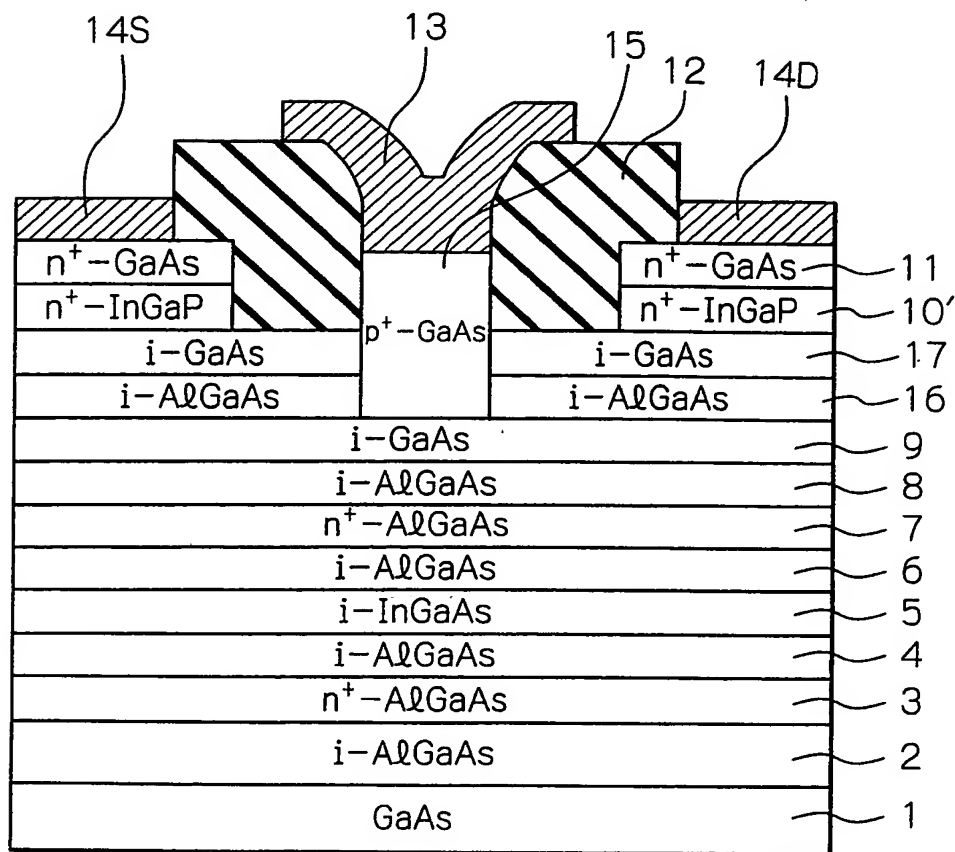


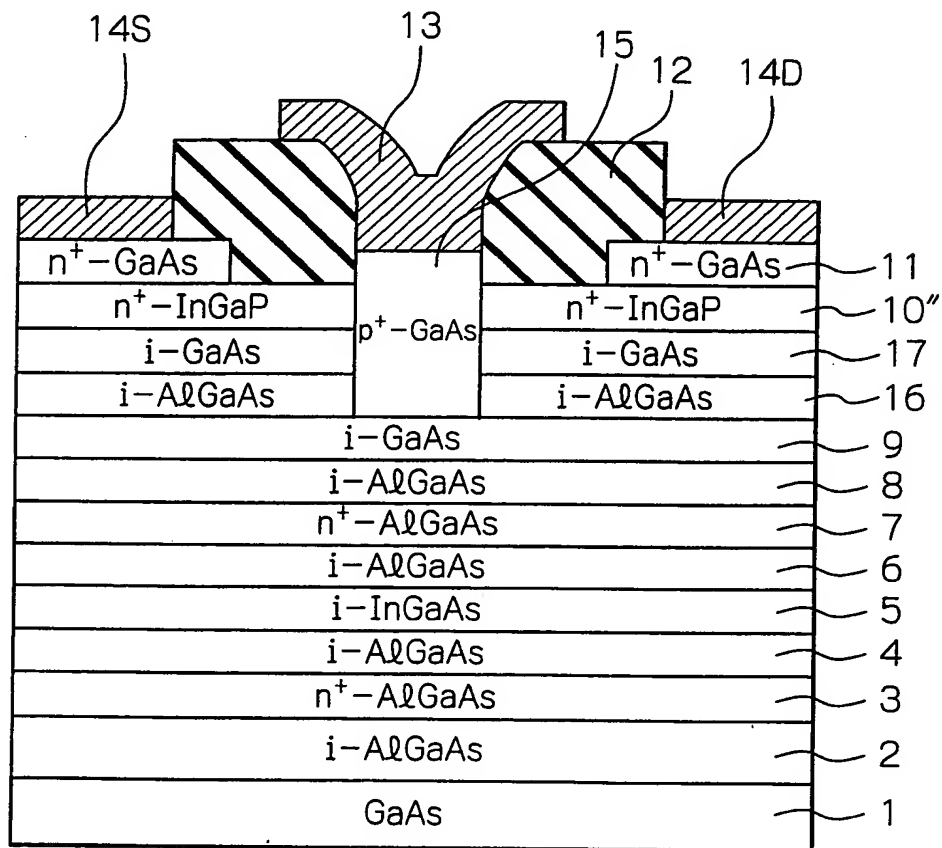
Fig. 11



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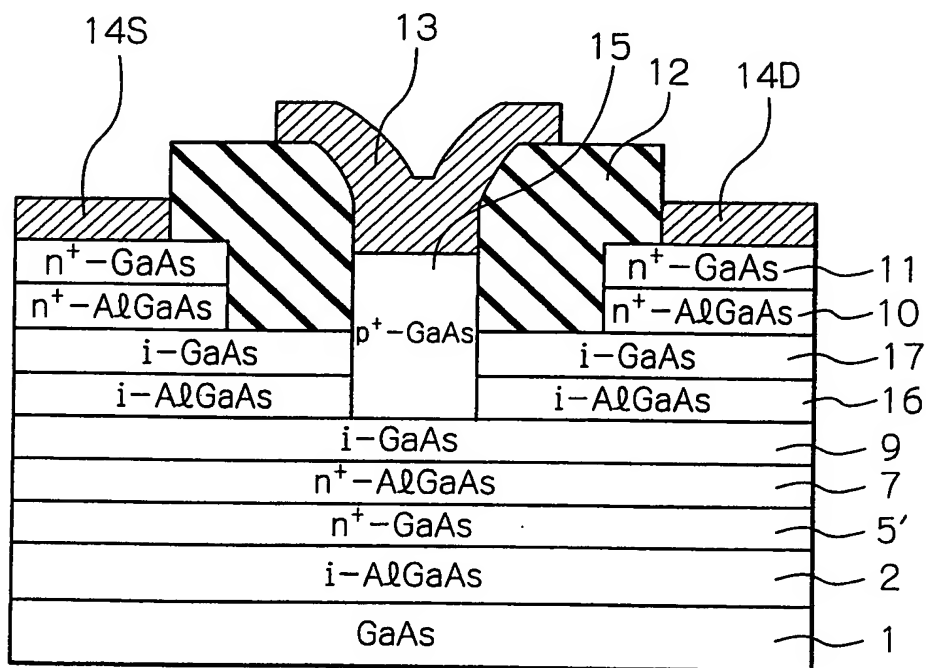
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Fig. 13



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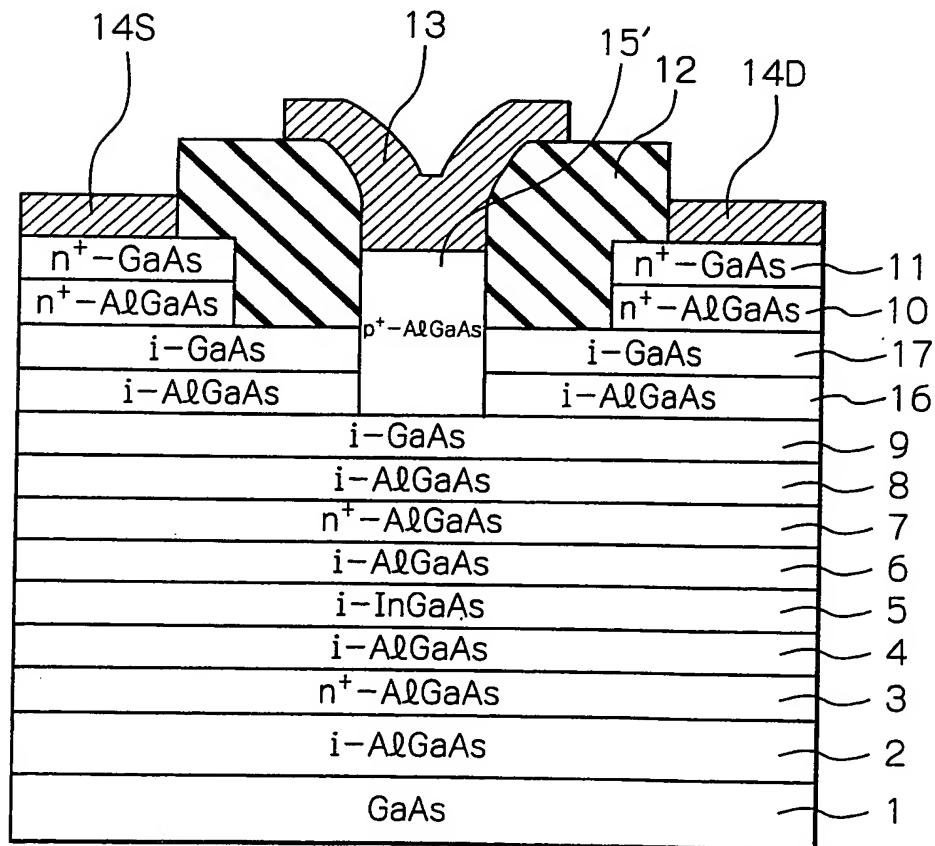
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Fig. 14



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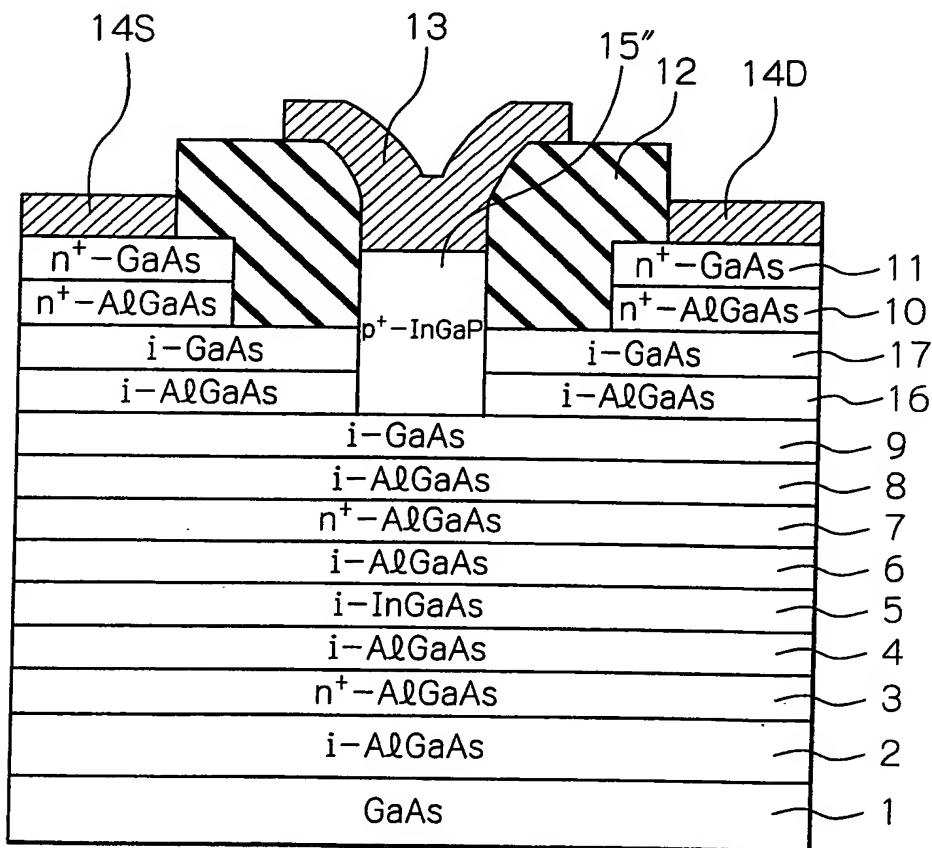
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Fig. 15

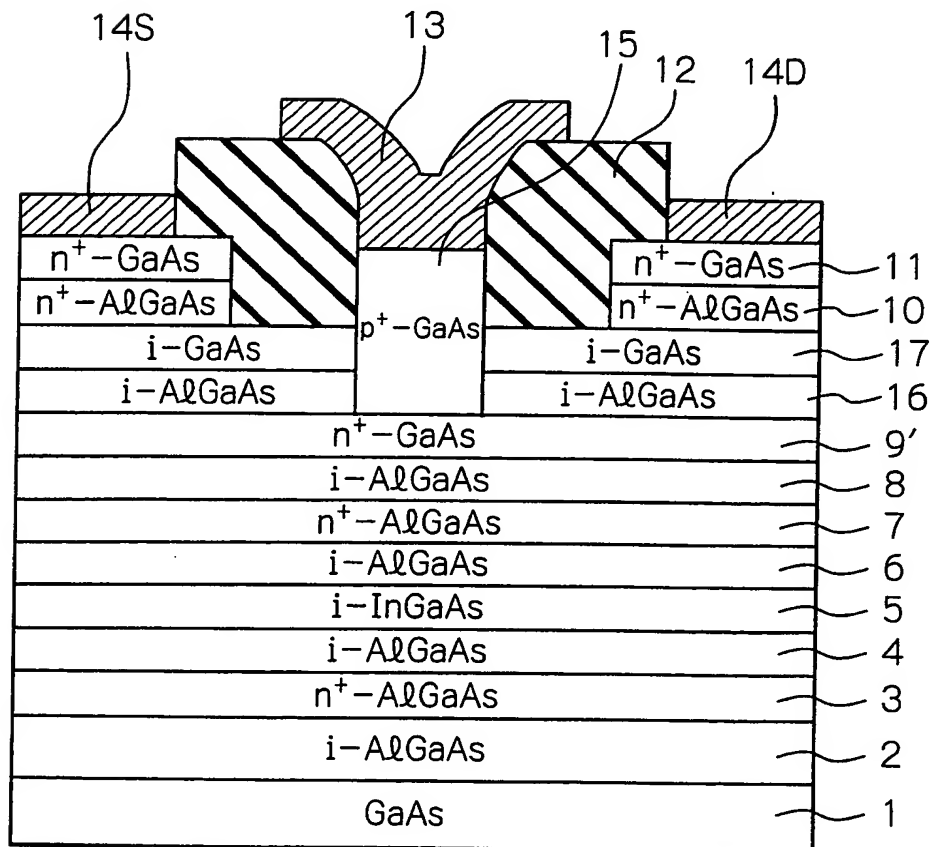


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Fig. 16



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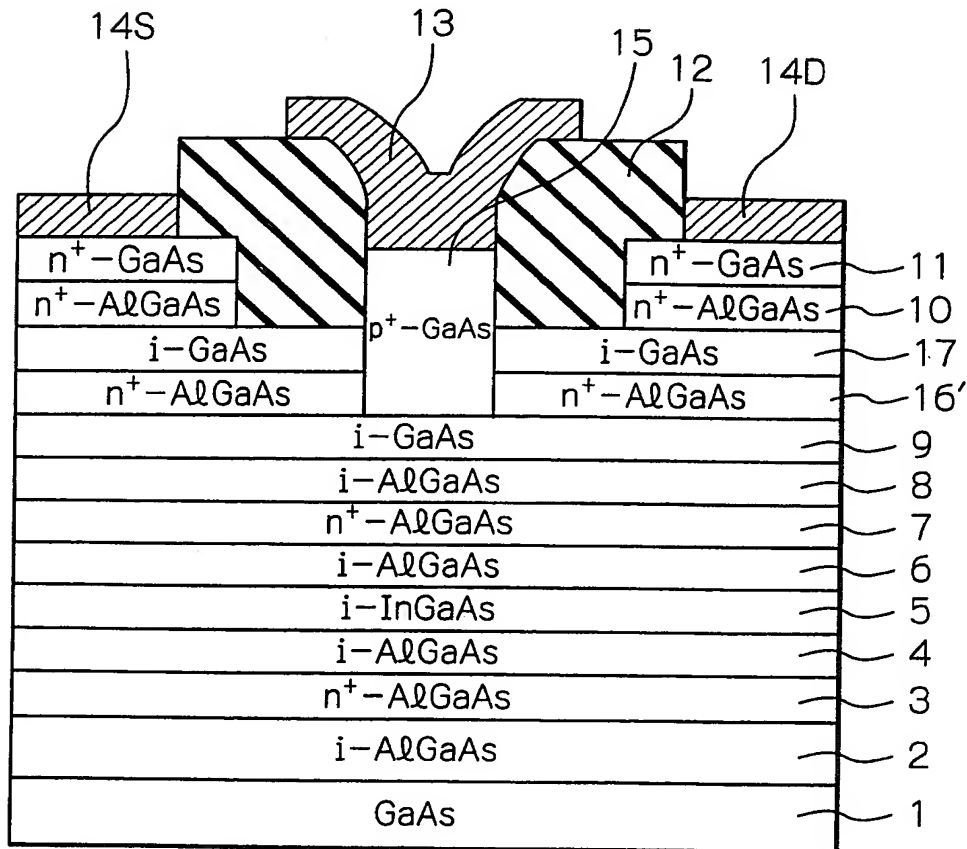
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Fig. 17



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Fig. 18

